

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	12	("4927770" "5053083" "5057439" "5164019" "5360990" "5369291" "6274402" "6313395" "6333457" "6337283" "6387726" "6423568").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 11:50
S2	0	S1 and tunnel	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 11:57
S3	8126	tunnel near oxide	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 11:57
S4	18	S3 and 136/243-265. ccls.	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 11:57
S5	7448	136/243-265.ccls.	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 12:35
S7	5	(solar or photovoltaic) and (tunnel near oxide)	FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/15 12:37
S8	83	S6 and (polysilicon or p silicon)	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 12:39
S9	171	S5 and polysilicon	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 12:53
S10	705	S5 and (back near contact)	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 13:18
S11	41	S5 and ((tunnel or barrier) near1 oxide)	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 14:21
S12	4	S1 and barrier	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 14:36
S13	0	S1 and thin oxide	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 14:38
S14	114	S5 and (thin near1 oxide near1 layer)	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/15 14:39
S15	0	"200266478"	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/16 10:36
S16	1	"1198014"	EPO	ADJ	ON	2008/04/16 10:37

S17	0	"4776894"	EPO	ADJ	ON	2008/04/16 10:37
S18	13	"4776894"	US-PGPUB; USPAT	ADJ	ON	2008/04/16 10:38
S19	10	("4776894").URPN.	USPAT	ADJ	ON	2008/04/16 11:13
S20	5070	136/243-265.ccls.	USPAT	ADJ	ON	2008/04/16 11:52
S21	136	S20 and atomic percent	USPAT	ADJ	ON	2008/04/16 11:52
S22	6	S20 and (atomic percent with (o or oxygen))	USPAT	ADJ	ON	2008/04/16 11:53
S23	48782	crystal\$5 with amorph\$5	USPAT	ADJ	ON	2008/04/17 08:36
S24	11348	S23 with silicon	USPAT	ADJ	ON	2008/04/17 08:36
S25	796	S24 and 136/243- 265.ccls.	USPAT	ADJ	ON	2008/04/17 08:36
S26	0	S25 and palsma CVD	USPAT	ADJ	ON	2008/04/17 08:39
S27	415	S25 and CVD	USPAT	ADJ	ON	2008/04/17 08:40
S28	26	pecvd and S25	USPAT	ADJ	ON	2008/04/17 08:42
S29	0	"crystal\$5 and amorph\$5"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:33
S30	5640	both with crystal\$5 with amorph\$5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:33
S31	323	S30 and (solar or photovoltaic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:34

S32	283	S31 and silicon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:34
S33	781	both with crystal\$5 with amorph\$5 with silicon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:34
S34	111	S33 and (solar or photovoltaic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:34
S35	58	S34 and (cvd or plasama or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:38
S36	72	S34 and (cvd or plasma or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:41
S37	757	multi step with (cvd or plasma or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:49
S38	41	S37 and (multijunction or stacked)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:49
S39	1	S37 and 136/243- 265.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:52

S40	1197	mixing ratio same (cvd or plasma or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:53
S41	26	(mixing ratio with dop \$5) same (cvd or plasma or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:54
S42	2	(mixing ratio with dop \$5) same ((cvd near1 plasma) or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:56
S43	4784	(remove or take or release) same ((cvd near1 plasma) or pecvd)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:58
S44	330	(remove or take or release) same ((cvd near1 plasma) or pecvd) and (solar or photovoltaic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:59
S45	124	((remove or take or release) same ((cvd near1 plasma) or pecvd) same silicon) and (solar or photovoltaic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 09:59
S46	481	((step) same ((cvd near1 plasma) or pecvd) same silicon) and (solar or photovoltaic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 10:03
S47	0	"200166478"	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/17 11:07
S48	0	"2001266478"	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/17 11:07
S49	0	"2002166478"	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/17 11:07
S50	0	"2002?66478"	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/17 11:07

S51	0	"2002"?66478?	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/04/17 11:08
S52	0	"2002261308"	US-PGPUB	ADJ	ON	2008/04/17 11:08
S53	2	"2002-261308"	US-PGPUB	ADJ	ON	2008/04/17 11:08
S54	1	"1198014"	EPO	ADJ	ON	2008/04/17 11:10
S55	7	"2000138384" or "2002261305" or "595126" or "2003258297" or "2000269528" or "2003142709" or "2003124481"	JPO	ADJ	ON	2008/04/17 11:12
S56	14	"1198014"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 14:45
S57	2	"6632993"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 14:48
S58	10222	136/243-265.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/04/17 14:54
S59	6876	136/243-265.ccls.	US-PGPUB; USPAT	ADJ	ON	2008/04/17 14:54
S60	1171	S59 and (groove or crevice or crack)	US-PGPUB; USPAT	ADJ	ON	2008/04/17 14:54
S61	230	S60 and (tandem or multijunction)	US-PGPUB; USPAT	ADJ	ON	2008/04/17 14:55
S62	112	S60 and (tandem or multijunction) and cvd	US-PGPUB; USPAT	ADJ	ON	2008/04/17 14:57
S63	112	S60 and (tandem or multijunction) and cvd and silicon	US-PGPUB; USPAT	ADJ	ON	2008/04/17 14:59

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